

**Amendments to the Claims**

Claim 1 (Currently amended): An RF plasma generator comprising:

- a) a variable frequency RF generator, comprising ~~an H-bridge and~~ an RF output, that generates electromagnetic radiation having a power;
- b) a matching network comprising at least one variable impedance component, the matching network including a first port that is electromagnetically coupled to the output of the RF generator and a second port, the variable impedance component providing an electrically controllable variable capacitance;
- c) a load that is electromagnetically coupled to the second port of the matching network; and
- d) a plasma chamber for containing a plasma having a power, the plasma chamber being electromagnetically coupled to the load, the plasma chamber receiving electromagnetic radiation having a power from the load, wherein adjusting at least one of the frequency of the RF generator and the variable impedance component in the matching network changes the power in the plasma.

Claim 2 (Original): The RF plasma generator of claim 1 wherein the load is reactive.

Claim 3 (Original): The RF plasma generator of claim 1 wherein the matching network transforms the impedance of the reactive load to a substantially real impedance.

Claim 4 (Original): The RF plasma generator of claim 1 wherein the load comprises an inductive load.

Claim 5 (Original): The RF plasma generator of claim 1 wherein the load comprises a capacitive load.

Claim 6 (Original): The RF plasma generator of claim 1 wherein the adjusting the at least one of the frequency of the RF generator and the variable impedance component in the matching network substantially matches an impedance of the load to an output impedance of the RF generator.

Claim 8 (Original): The RF plasma generator of claim 1 wherein the matching network has a substantially resistive impedance at a frequency of the electromagnetic radiation.

Claim 9 (Original): The RF plasma generator of claim 1 wherein the matching network comprises a series combination of an amplifier and a variable capacitance capacitor.

Claim 10 (Cancelled)

Claim 11 (Original): The RF plasma generator of claim 1 wherein the RF generator and the matching network are physically integrated in a device housing.

Claim 12 (Original): The RF plasma generator of claim 1 further comprising a sensor that measures power delivered to the load.

Claim 13 (Original): The RF plasma generator of claim 1 wherein the at least one of the frequency of the RF generator and the variable impedance component in the matching network is adjusted in response to a measurement of the sensor.

Claim 14 (Original): The RF plasma generator of claim 13 wherein the at least one of the frequency of the RF generator and the variable impedance component in the matching network is adjusted to minimize power reflected from the plasma.

Claim 15 (Original): The RF plasma generator of claim 13 wherein the at least one of the frequency of the RF generator and the variable impedance component in the matching network is adjusted to maximize power reflected from the plasma.

Claim 16 (Original): The RF plasma generator of claim 1 wherein the plasma has a power that is related to the power of the electromagnetic radiation that is coupled from the load to the plasma.

Claim 17 (Original): The RF plasma generator of claim 1 wherein the matching network comprises switching transistors.

Claim 18-31 (Cancelled)

Claim 32 (Previously presented): An RF plasma generator comprising:

- a) an RF generator including an RF output that generates electromagnetic radiation at a frequency;
- b) a matching network comprising a 3-port solid state device that electrically controls a change of a capacitance of a component in the matching network, an

impedance of the matching network being substantially resistive at the frequency of the RF electromagnetic radiation, the matching network including a first port that is electromagnetically coupled to the output of the RF generator and a second port;

- c) a load that is electromagnetically coupled to the second port of the matching network; and
- d) a plasma chamber for containing a plasma therein, the plasma chamber being electromagnetically coupled to the load.

Claim 33 (Currently amended): An RF plasma generator comprising:

- a) an RF generator, comprising an ~~H-bridge~~ and an RF output, that generates electromagnetic radiation having a power;
- b) a matching network comprising a series combination of an amplifier and an electrically controllable variable capacitance capacitor, the matching network including a first port that is electromagnetically coupled to the output of the RF generator and a second port;
- c) a load that is electromagnetically coupled to the second port of the matching network; and
- d) a plasma chamber for containing a plasma having a power, the plasma chamber being electromagnetically coupled to the load, the plasma chamber receiving electromagnetic radiation having a power from the load, wherein adjusting at least one of the frequency of the RF generator and the variable impedance component in the matching network changes the power in the plasma.

Claim 34 (Cancelled)

Claim 35 (Previously presented): An RF plasma generator comprising:

- a) a variable frequency RF generator including an RF output that generates an RF signal having a power;
- b) a matching network comprising at least one variable impedance component and a 3-port solid state device that electrically controls a change of a capacitance of a component in the matching network, the matching network including a first port that receives the RF signal and a second port;
- c) a load that is electrically coupled to the second port of the matching network; and

- d) a plasma chamber for containing a plasma having a power, the plasma chamber being electromagnetically coupled to the load via the RF signal, wherein adjusting at least one of the frequency of the RF generator and the variable impedance component in the matching network changes the power in the plasma.

Claim 36 (new): An RF plasma generator comprising:

- a) a variable frequency RF generator, comprising an RF output, that generates electromagnetic radiation having a power;
- b) a matching network comprising at least one variable impedance component, the matching network including a first port that is electromagnetically coupled to the output of the RF generator and a second port, the variable impedance component providing an electrically controllable variable impedance;
- c) a load that is electromagnetically coupled to the second port of the matching network; and
- d) a plasma chamber for containing a plasma having a power, the plasma chamber being electromagnetically coupled to the load, the plasma chamber receiving electromagnetic radiation having a power from the load, wherein adjusting at least one of the frequency of the RF generator and the variable impedance component in the matching network changes the power in the plasma.

Claim 37 (new): The RF plasma generator of claim 36 wherein the variable impedance component comprises a variable capacitance component.